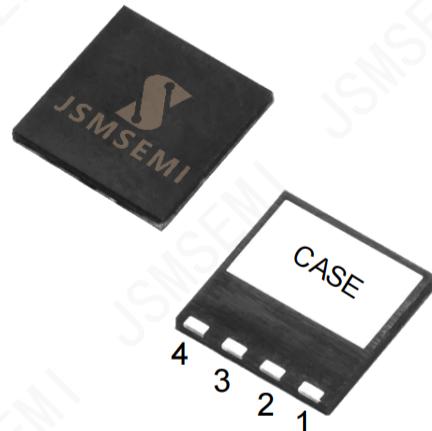


Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on V_F
- Temperature Independent Switching Behavior
- High surge current capability



Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

Applications

- PC Power
- Server Power Supply
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



Maximum Ratings (T_c=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}		650	V
Peak Reverse Surge Voltage	V _{RSM}		650	V
DC Blocking Voltage	V _R		650	V
Continuous Forward Current	I _F	T _c =25°C T _c =135°C T _c =140°C	28 11 10	A
Non repetitive Forward Surge Current	I _{FSM}	T _c = 25°C, t _p =10 ms, Half Sine Pulse T _c = 110°C, t _p =10 ms, Half Sine Pulse T _c = 25°C, t _p =10 μs, Square	50 40 300	A
Repetitive peak Forward Surge Current	I _{FRM}	T _c = 25°C, t _p =10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse T _c = 110°C, t _p =10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	40 30	A
Total power dissipation	P _D	T _c =25°C	83	W
Operating Junction Temperature	T _J		-55 to 175	°C
Storage Temperature	T _{STG}		-55 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	V_{DC}	$I_R = 250\mu A, T_J = 25^\circ C$	650			V
Forward Voltage	V_F	$I_F = 10A, T_J = 25^\circ C$		1.5	1.8	V
		$I_F = 10A, T_J = 125^\circ C$		1.65		
		$I_F = 10A, T_J = 175^\circ C$		1.8		V
Reverse Current	I_R	$V_R = 650V, T_J = 25^\circ C$		10	80	uA
		$V_R = 650V, T_J = 125^\circ C$		68		uA
		$V_R = 650V, T_J = 175^\circ C$		190		uA
Total Capacitive Charge	Q_C	$V_R = 400V$ $T_J = 25^\circ C$		23		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^\circ C$, Freq = 1MHz		387		pF
		$V_R = 200V, T_J = 25^\circ C$, Freq = 1MHz		48		
		$V_R = 400V, T_J = 25^\circ C$, Freq = 1MHz		33		

Note: This is a majority carrier diode, so there is no reverse recovery charge

Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.8		°C/W

Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SSTPSC10065DLF	DFN8080-4L	SC6D10065Q	-55 to 175°C	1	T&R,3000	Rohs

Typical Electrical Curves

Figure 1. Forward Characteristics

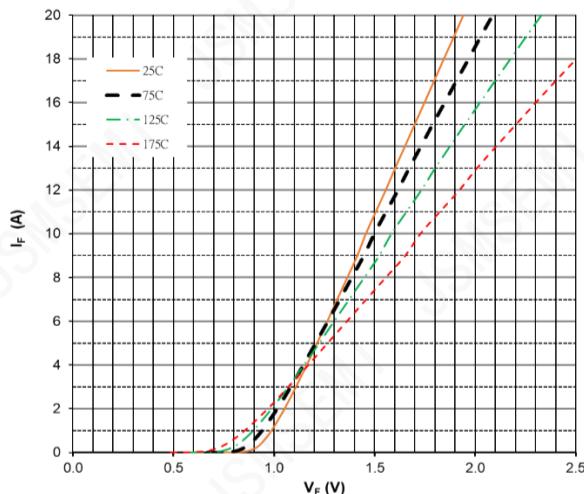


Figure 2. Forward Characteristics

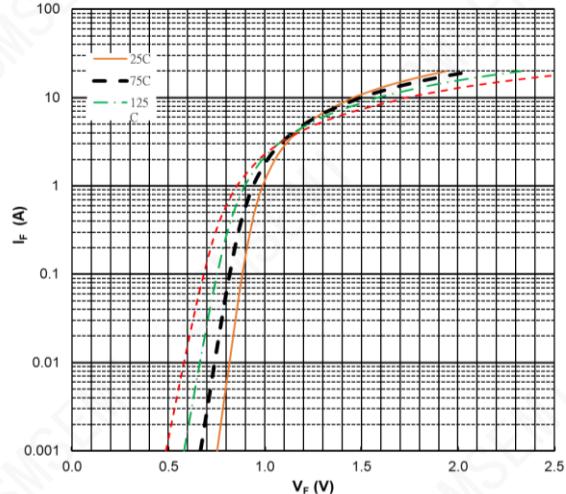


Figure 3. Reverse Characteristics

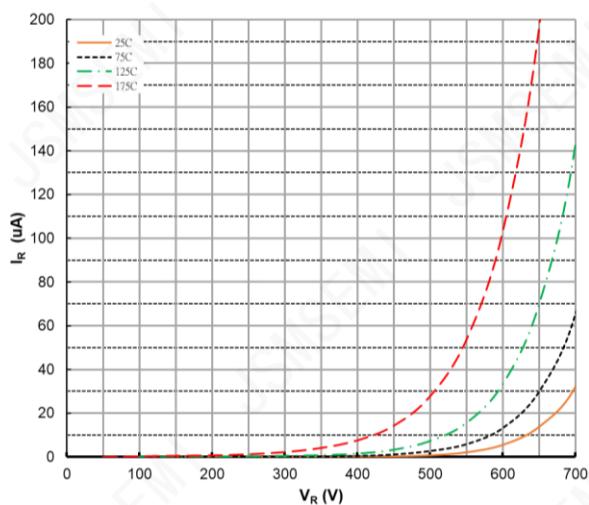


Figure 5. Capacitance vs Reverse Voltage

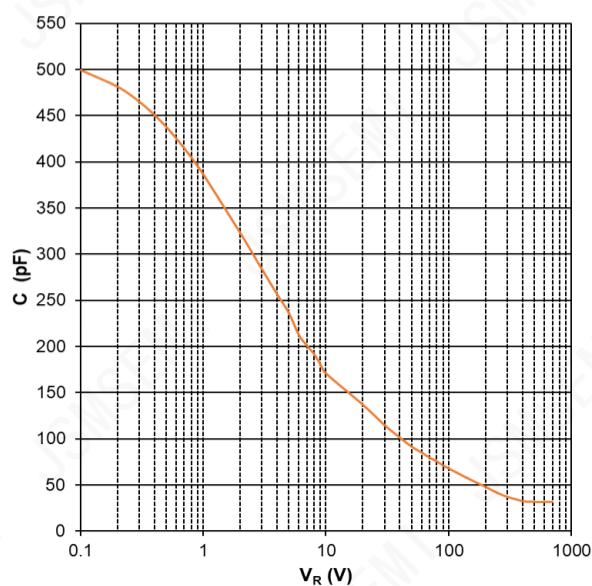


Figure 4. Power Derating

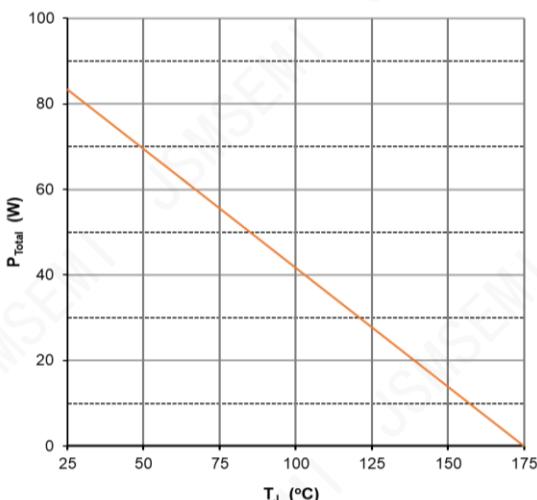
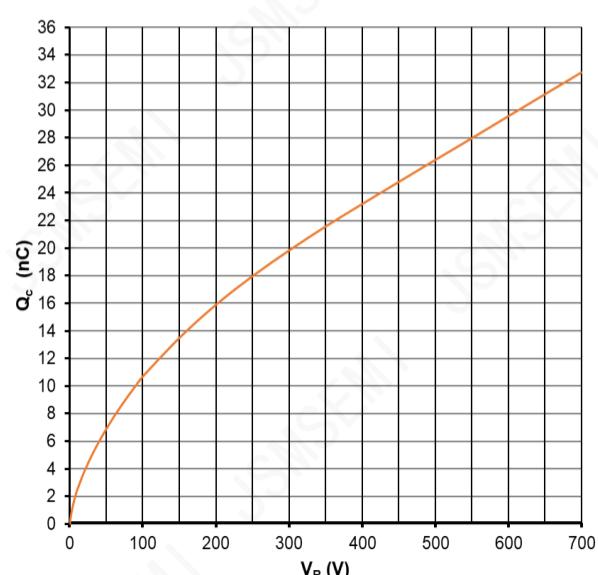
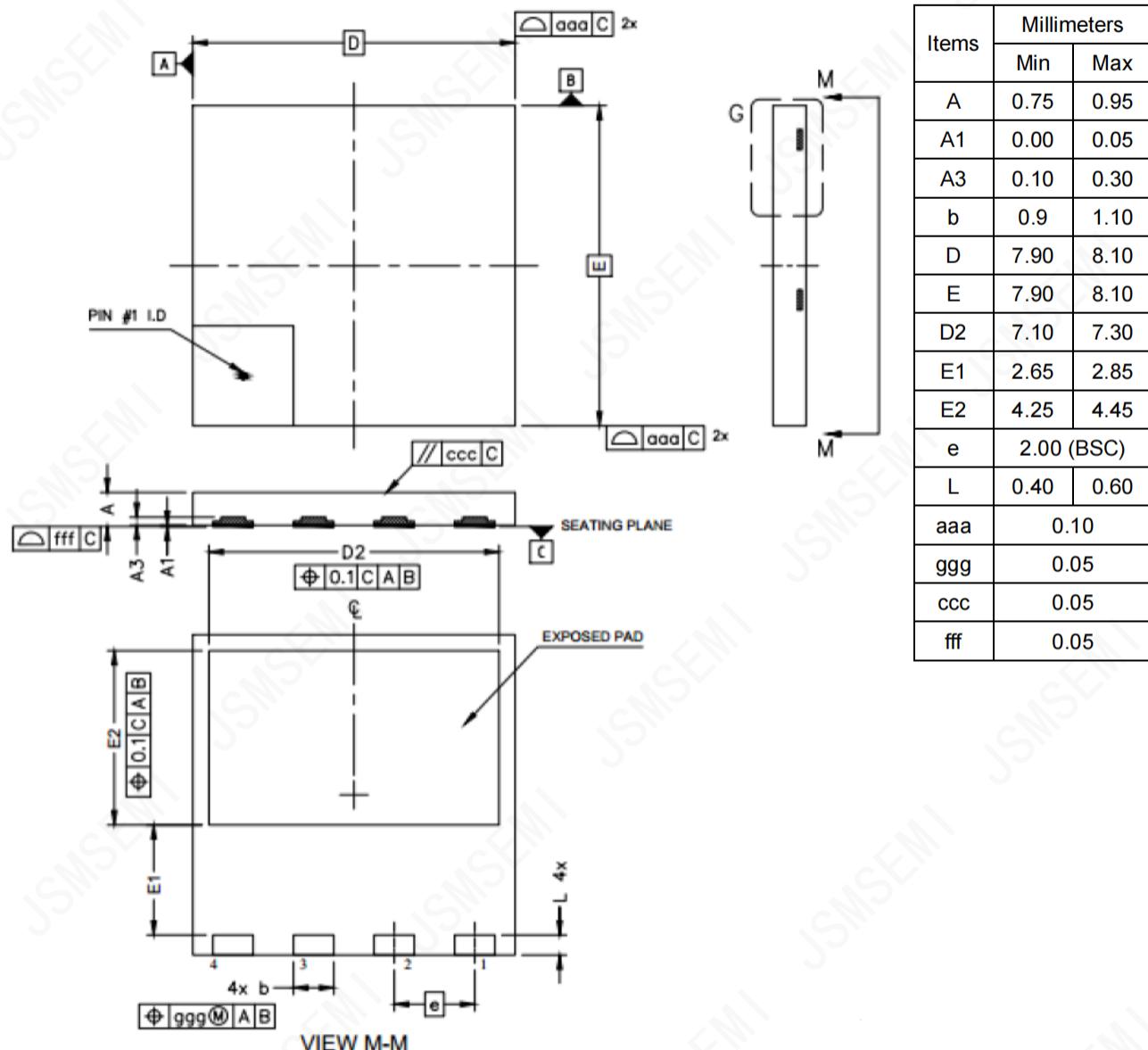


Figure 6. Recovery Charge vs Reverse Voltage



Package Dimensions

(DFN 8x8 Package)



Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2022

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